

L Number	Hits	Search Text	DB	Time stamp
1	4263	438/201,211,216,241,257,258,260-266,591,593.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:09
2	5167	257/239,261,298,315-326.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:09
3	8777	438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:10
4	625	(438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.) and ((first adj gate) with (second adj gate) with substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:24
5	555	((438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.) and ((first adj gate) with (second adj gate) with substrate)) and (dop\$4 diffus\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:11
6	42	((438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.) and ((first adj gate) with (second adj gate) with substrate)) and (dop\$4 diffus\$3)) and ((first adj (insulat\$3 dielectric) adj (film layer)) with (nitrogen (silicon adj nitride)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:17
7	6	((438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.) and ((first adj gate) with (second adj gate) with substrate)) and (dop\$4 diffus\$3)) and ((first adj (insulat\$3 dielectric) adj (film layer)) with nitrogen)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:21
8	4	((438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.) and ((first adj gate) with (second adj gate) with substrate)) and (dop\$4 diffus\$3)) and ((first adj (insulat\$3 dielectric) adj (film layer)) with hydrogen)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:25
9	395882	438/\$.ccls. 257/\$.ccls. 365/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:24
10	2402	(438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and ((first adj gate) with (second adj gate) with substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:30
11	12	((438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and ((first adj gate) with (second adj gate) with substrate)) and ((first adj (insulat\$3 dielectric) adj (film layer)) with hydrogen)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:29
12	515	(438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and ((first adj (insulat\$3 dielectric) adj (film layer)) with (nitrogen hydrogen))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:39

13	32	((438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and ((first adj (insulat\$3 dielectric) adj (film layer)) with (nitrogen hydrogen))) and ((first adj gate) with (second adj gate) with substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:31
14	9	(438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and ((first adj (insulat\$3 dielectric) adj (film layer)) with (embed\$4 near2 between) with gate\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:41
15	42	(438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and (((insulat\$3 dielectric) adj (film layer)) with (embed\$4 near2 between) with gate\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:57
16	17	("5338700"   "5374580"   "5401681"   "5604147"   "5789304"   "5824582"   "5998257"   "6001685"   "6020234"   "6023084"   "6046093"   "6077742"   "6080620"   "6100129"   "6110774"   "6221711"   "6232176").PN.	USPAT	2004/04/28 10:48
17	61	(((insulat\$3 dielectric) adj (film layer)) with (embed\$4 near2 between) with gate\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/28 10:57